



40V COMPLEMENTARY NPN-PNP SMALL SIGNAL TRANSISTOR IN SOT363

Features

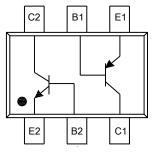
- Complementary Pair One 3904-Type NPN One 3906-Type PNP
- Ultra-Small Surface Mount Package
- **Epitaxial Planar Die Construction**
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (MMDT3946Q)



Top View

Mechanical Data

- Case: SOT363 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)



E1, B1, C1 = PNP 3906 E2, B2, C2 = NPN 3904

Quantity Per Reel

3.000

Device Schematic and Pinout Top View

Ordering Information (Note 4) Part Number Compliance Marking **Reel Size (inches)** Tape Width (mm) MMDT3946-7-F AEC-Q101 K46 8

MMDT3946-7R-F AEC-Q101 K46 8 3,000 7 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

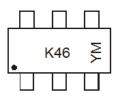
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



K46 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key												
Year	2018		2019	2020		2021	2022		2023	2024		2025
Code	F		G	Н			J		K	L		М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings, NPN 3904 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	lc	200	mA

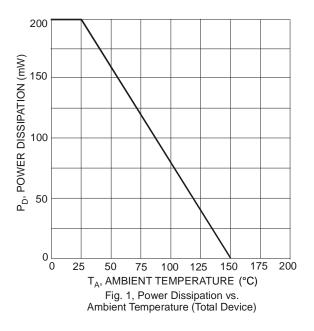
Absolute Maximum Ratings, PNP 3906 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current	Ic	-200	mA

Thermal Characteristics, Total Device (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

Notes: 5. For a device mounted on minimum recommended pad layout that is on a single-sided 0.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.





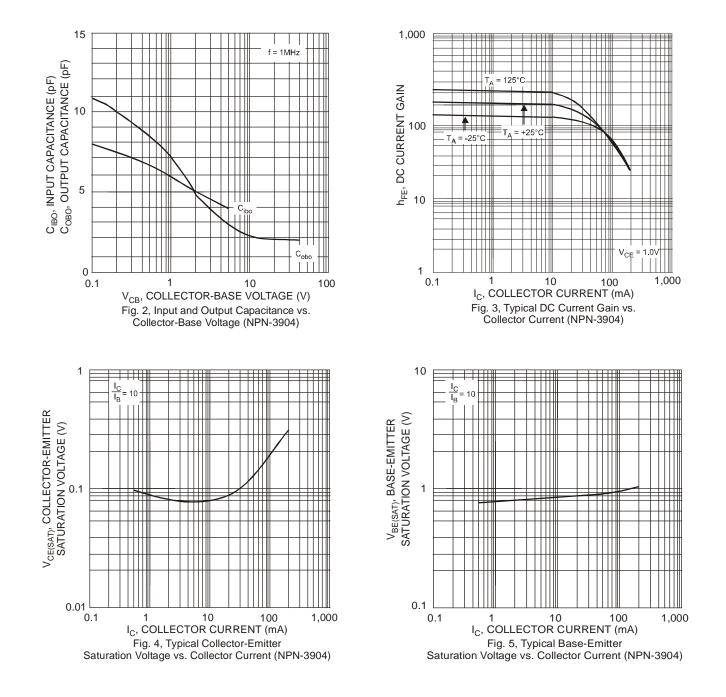
Electrical Characteristics, NPN 3904 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)			•		
Collector-Base Breakdown Voltage	ВV _{CBO}	60	_	V	$I_{C} = 10 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	40	_	V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	_	V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector Cutoff Current	ICEX	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
Base Cutoff Current	I _{BL}	_	50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 6)					•
Static Forward Current Transfer Ratio	hfe	40 70 100 60 30	 300 		$\begin{split} I_{C} &= 100 \mu A, V_{CE} = 1.0 V \\ I_{C} &= 1.0 m A, V_{CE} = 1.0 V \\ I_{C} &= 10 m A, V_{CE} = 1.0 V \\ I_{C} &= 50 m A, V_{CE} = 1.0 V \\ I_{C} &= 100 m A, V_{CE} = 1.0 V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.20 0.30	V	$I_C = 10mA$, $I_B = 1.0mA$ $I_C = 50mA$, $I_B = 5.0mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.65	0.85 0.95	V	$I_{C} = 10mA, I_{B} = 1.0mA$ $I_{C} = 50mA, I_{B} = 5.0mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	_	4.0	pF	$V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$
nput Capacitance	C _{ibo}	_	8.0	pF	$V_{EB} = 0.5V$, f = 1.0MHz, I _C = 0
nput Impedance	h _{ie}	1.0	10	kΩ	
Voltage Feedback Ratio	h _{re}	0.5	8.0	x 10 ⁻⁴	$V_{CE} = 10V, I_{C} = 1.0mA,$
Small Signal Current Gain	h _{fe}	100	400	—	f = 1.0 kHz
Output Admittance	h _{oe}	1.0	40	μS	
Current Gain-Bandwidth Product	f _T	300	—	MHz	$V_{CE} = 20V$, $I_C = 20mA$, f = 100MHz
Noise Figure	NF		5.0	dB	$V_{CE} = 5.0V, I_C = 100\mu A,$ $R_S = 1.0k\Omega, f = 1.0kHz$
SWITCHING CHARACTERISTICS			·	·	
Delay Time	t _d	_	35	ns	$V_{CC} = 3.0V, I_{C} = 10mA,$
Rise Time	tr		35	ns	$V_{BE(off)} = 0.5V, I_{B1} = 1.0mA$
Storage Time	ts		200	ns	V _{CC} = 3.0V, I _C = 10mA,
Fall Time	t _f		50	ns	$I_{B1} = -I_{B2} = 1.0 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics, NPN 3904 (@T_A = +25°C, unless otherwise specified.)





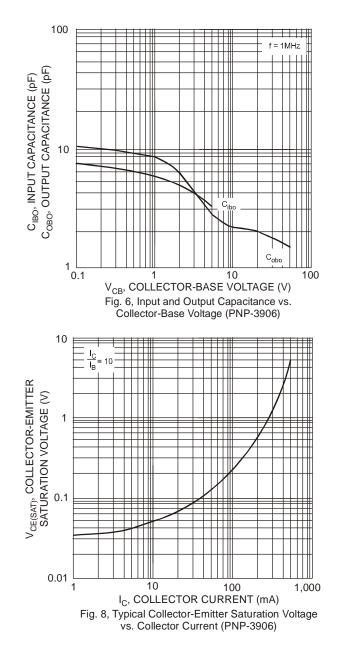
Electrical Characteristics, PNP 3906 (@T_A = +25°C, unless otherwise specified.)

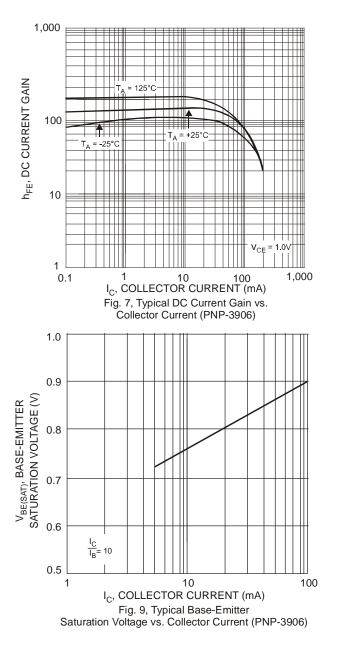
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					-
Collector-Base Breakdown Voltage	ВV _{CBO}	-40	_	V	$I_{\rm C} = -10 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	-40	_	V	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	-5.0	_	V	$I_{E} = -10\mu A, I_{C} = 0$
Collector Cutoff Current	ICEX	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$
Base Cutoff Current	I _{BL}	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$
ON CHARACTERISTICS (Note 6)					-
Static Forward Current Transfer Ratio	h _{FE}	60 80 100 60 30	 300 	_	$\begin{split} I_{C} &= -100 \mu A, V_{CE} = -1.0V \\ I_{C} &= -1.0 m A, V_{CE} = -1.0V \\ I_{C} &= -10 m A, V_{CE} = -1.0V \\ I_{C} &= -50 m A, V_{CE} = -1.0V \\ I_{C} &= -100 m A, V_{CE} = -1.0V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.25 -0.40	V	$I_{C} = -10mA$, $I_{B} = -1.0mA$ $I_{C} = -50mA$, $I_{B} = -5.0mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.65	-0.85 -0.95	V	$I_{C} = -10mA$, $I_{B} = -1.0mA$ $I_{C} = -50mA$, $I_{B} = -5.0mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	_	4.5	pF	$V_{CB} = -5.0V$, f = 1.0MHz, I _E = 0
nput Capacitance	C _{ibo}	_	10	pF	$V_{EB} = -0.5V$, f = 1.0MHz, I _C = 0
nput Impedance	h _{ie}	2.0	12	kΩ	
/oltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴	$V_{CE} = -10V, I_{C} = -1.0mA,$
Small Signal Current Gain	h _{fe}	100	400	—	f = 1.0 kHz
Dutput Admittance	h _{oe}	3.0	60	μS	
Current Gain-Bandwidth Product	f⊤	250	_	MHz	$V_{CE} = -20V$, $I_C = -10mA$, f = 100MHz
Noise Figure	NF		4.0	dB	$V_{CE} = -5.0V, I_C = -100\mu A,$ $R_S = 1.0k\Omega, f = 1.0kHz$
SWITCHING CHARACTERISTICS					-
Delay Time	t _d		35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
Rise Time	tr		35	ns	$V_{BE(off)} = -0.5V, I_{B1} = -1.0mA$
Storage Time	t _s		225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$
all Time	t _f		75	ns	$I_{B1} = -I_{B2} = -1.0$ mA

Notes: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics, PNP 3906 (@T_A = +25°C, unless otherwise specified.)

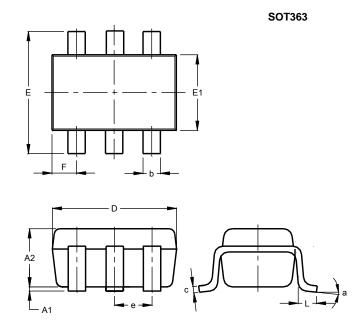






Package Outline Dimensions

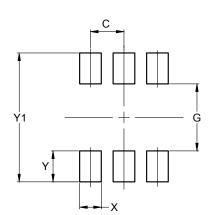
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.10	0.30	0.25				
С	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	0.650 BSC						
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)		
С	0.650		
G	1.300		
Х	0.420		
Y	0.600		
Y1	2.500		

SOT363



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